

ABSTRACT OF THE DISCLOSURE

There is provided a liquid crystal display device that can obtain a high light utilization efficiency and a sufficient supplementary capacitance without reducing an aperture rate of pixels and is able to attain higher resolution. A silicon nitride film 22 that serves as a supplementary capacitance use transparent insulating film is formed under a pixel electrode 3. A common electrode 21 that is made of ITO and is connected to a potential common to an opposite electrode is formed under the silicon nitride film 22. The pixel electrode 3, the silicon nitride film 22 and the common electrode 21 constitute the supplementary capacitance, and the pixel electrode 3, the silicon nitride film 22 and the common electrode 21 are each made to have a film thickness such that a transmittance is increased by interference at a specified wavelength.

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